

# SANYO Semiconductors DATA SHEET

SBE602 — Schottky Barrier Diode (Twin Type · Cathode Common)

# 30V, 70mA Rectifier

# **Applications**

· High frequency rectification (switching regulators, converters, choppers).

#### **Features**

- Low forward voltage (VF max=0.55V).
- Fast reverse recovery time (t<sub>rr</sub> max=10ns).
- · Low switching noise.
- · Low leakage current and high reliability due to highly reliable planar structure.
- Ultrasmall-sized package permitting SBE602-applied sets to be made small and slim.

# Absolute Maximum Ratings at Ta=25°C (Value per element)

Parameter	Symbol	Conditions	Ratings	Unit
Repetitive Peak Reverse Voltage	VRRM		30	٧
Nonrepetitive Peak Reverse Surge Voltage	VRSM		35	V
Average Output Current	lo		70	mA
Surge Forward Current	IFSM	50Hz sine wave, 1 cycle	2	Α
Junction Temperature	Tj		-55 to +125	°C
Storage Temperature	Tstg		-55 to +125	°C

#### **Electrical Characteristics** at Ta=25°C (Value per element)

Parameter	Symbol	Conditions	Ratings			Unit
			min	typ	max	Oill
Reverse Voltage	٧R	I <sub>R</sub> =20μA	30			V
Forward Voltage	VF	IF=70mA			0.55	V
Reverse Current	I <sub>R</sub> 1	V <sub>R</sub> =2V			75	nA
	I <sub>R</sub> 2	V <sub>R</sub> =15V			5.0	μΑ
Interterminal Capacitance	С	V <sub>R</sub> =10V, f=1MHz		5.5		pF
Reverse Recovery Time	t <sub>rr</sub>	I <sub>F</sub> =I <sub>R</sub> =10mA, See specified Test Circuit.			10	ns
Therrmal Resistance	Rth(j-a)	Mounted in Cu-foiled area of 0.72mm <sup>2</sup> X0.03mm		300		°C/W
		on glass epoxy board				

Marking: SQ

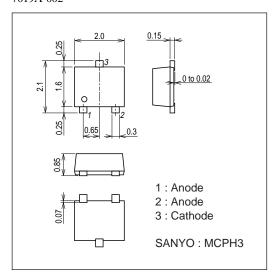
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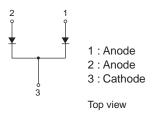
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### **Package Dimensions**

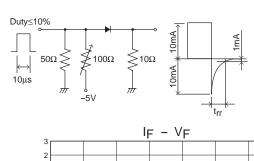
unit: mm (typ) 7019A-002

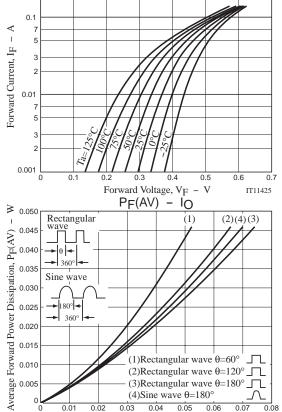


#### **Electrical Connection**



# trr Test Circuit





(2)Rectangular wave  $\theta=120^{\circ}$ 

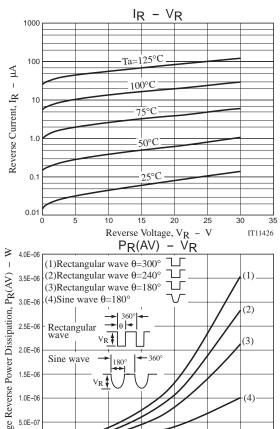
(3)Rectangular wave θ=180° □□

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(4)Sine wave  $\theta=180^{\circ}$ 

0.03 0.04 0.05 0.06 Average Output Current,  $I_{\mbox{O}}$  – A

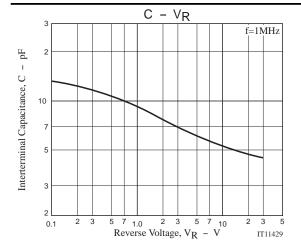


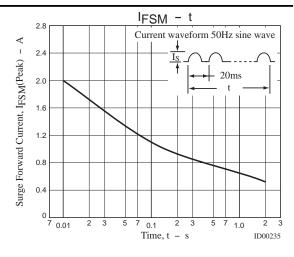


Peak Reverse Voltage,  $V_R - V$ 

IT11428

#### **SBE602**





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